Spin field effect transistors with ultracold atoms

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We propose a method of constructing cold atom analogs of the spintronic device known as the Datta-Das transistor (DDT), which despite its seminal conceptual role in spintronics, has never been successfully realized with electrons. We propose two alternative schemes for an atomic DDT, both of whi
h are based on the experimental setup for tripod stimulated Raman adiabati passage. Both setups involve atomic beams incident on a series of laser fields mimicking the relativistic spin orbit oupling for ele
trons that is the operating me
hanism of the DDT.

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The emerging technology of semiconductor spintronics exploits the ele
tron's spin degree of freedom, as well as its charge state. The first scheme for a semiconductor spintronic device was a spin field-effect transistor known as the Datta-Das transistor (DDT) (Fig. [1a](#page-0-0)) [\[1](#page-3-0)]. The eighteen years sin
e the theoreti
al proposal have seen numerous experimental efforts to construct the DDT. Various experimental obstacles, such as difficulties in spin injection, stray electric fields and insufficient quality of spin-orbit coupling, have prevented successful implementation of the DDT $[2]$ $[2]$.

Cold atom systems, in contrast with their electronic ounterparts, are highly ontrollable and tunable. This suggests the possibility of designing precise atomic analogs of electronic systems which, due either to fundamental physical limits or technological difficulties, are experimentally inaccessible in their original manifestations. The idea grows out of recent interest in "atomtronics," or building cold atom analogs of ordinary electronic materials, devices and circuits $[3, 4, 5]$ $[3, 4, 5]$ $[3, 4, 5]$ $[3, 4, 5]$ $[3, 4, 5]$ $[3, 4, 5]$. In particular, an atom diode has been proposed $[3]$ $[3]$ and realized $[5]$ $[5]$.

In this Letter, we identify a method for constructing a old atom analog of a Datta-Das transistor. The setup is based on a four level "tripod" scheme of atom-light coupling $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ involving three atomic ground states and one excited state (see Fig. [1b](#page-0-0)). Such tripod s
hemes are an extension of the usual three-level Λ-type setup for stimulated Raman adiabati passage (STIRAP) [\[3,](#page-3-2) 12], and are experimentally accessible in metastable Ne, 87 Rb and a number of other gases [\[8,](#page-3-7) [9](#page-3-8)]. The proposed device provides a robust method for atomic state manipulation that is immune to the inhomogeneities intrinsi to programmed Rabi pulses.

The sour
e terminal of an ele
troni DDT (Fig. [1a](#page-0-0)) is a ferromagnetic electrode that emits spin-polarized electrons. The DDT drain terminal, a ferromagnetic analyzer, acts as a spin filter. Between source and drain is a semi
ondu
ting gate region, in whi
h the gate-indu
ed electric field produces a Rashba spin-orbit coupling [\[13](#page-3-12)] for ele
trons. While passing through the gate region, the ele
tron's spin pre
esses; the ele
tron emerges at the

Figure 1: (a) Schematic of a DDT. "S" and "D" are ferromagnetic source and drain electrodes. In between is a semiconducting gate region, where the spin precesses by an amount which depends periodically on the tunable gate voltage V_q . This pre
ession results in a ontrollable urrent modulation at D. (b) ^A tripod s
heme of atomi energy levels, oupled by laser fields with Rabi frequencies Ω_i . (c,d) Two alternative setups for an atomic version of the DDT. Here, the source is a state-polarized atomic beam (blue), the gate is the intersection region of a configuration of laser beams (red), and the drain is an atomic state analyzer (green).

drain having undergone a spin rotation whi
h is tunable via the gate voltage. Since the drain passes only a certain spin direction, the drain current is an oscillating function of the gate voltage.

Our atomic analog of the DDT (Figs. 1c,d) uses a beam of atoms in pla
e of ele
trons. The two dark states in the tripod setup play the role of the electron's spin states, and the "source" is a dilute atomic beam. The "gate" region consists of crossed laser beams engineered to mimi Rashba or Rashba-like spin orbit ouplings $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$ $[14, 15, 16, 17, 18]$; the analog of the gate voltage an be tuned by varying the relative strengths of the

lasers. The drain is a state-selective atomic filter, such as a Stern-Gerla
h devi
e or radio-frequen
y or Raman outcoupler [\[19](#page-3-18)]. While the goal of this paper is to explore the possibility of onstru
ting the atomi analog of spintronic devices, the two dark states of the tripod atom can be considered qubit states $[20, 21, 22, 23]$ $[20, 21, 22, 23]$ $[20, 21, 22, 23]$ $[20, 21, 22, 23]$ $[20, 21, 22, 23]$ $[20, 21, 22, 23]$; in this context the atomi DDT represents a single-qubit phase gate for a dilute atomic beam. In contrast to typical single qubit gates, this setup does not involve time-dependent pulses, and the amount of the qubit rotation within the gate region is independent of the atom's velocity, due to the geometri nature of the pro
ess.

Tripod s
heme The proposed DDT implementations exploit the tripod scheme (Fig. [1b](#page-0-0),c) $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$ $[6, 7, 8, 9, 10, 11]$, in whi
h a four level atom feels two ounterpropagating stationary laser beams and a third orthogonal beam $[15, 17, 18]$ $[15, 17, 18]$ $[15, 17, 18]$ $[15, 17, 18]$ $[15, 17, 18]$ $[15, 17, 18]$. The lasers induce transitions between the ground states $|j\rangle$ $(j = 1, 2, 3)$ and an excited state $|0\rangle$ with spatially dependent Rabi frequencies Ω_1 = $|\Omega_1|e^{-i\kappa_0x}$, $\Omega_2 = |\Omega_2|e^{i\kappa_0x}$ and $\Omega_3 = |\Omega_3|e^{i\kappa_0z}$, κ_0 being a wave-number.

The ele
troni Hamiltonian of a tripod atom is, in the intera
tion representation and rotating wave approximation, $\hat{H}_e = -\hbar\Omega|B\rangle\langle 0| + \text{H.c., where } |B\rangle =$ $\left(\! \lfloor 1 \rangle \Omega^*_1 + \! \lfloor 2 \rangle \Omega^*_2 + \! \lfloor 3 \rangle \Omega^*_3 \right)/\Omega$ and $\Omega^2 = \! \lfloor \Omega_1 \! \rfloor^2 \! + \! \lfloor \Omega_2 \! \rfloor^2 \! + \! \lfloor \Omega_3 \! \rfloor^2$ \hat{H}_e has two degenerate dark states $|D_j\rangle$ containing no excited state contribution: $\hat{H}_e|D_j\rangle = 0, j = 1, 2$. An additional pair of bright eigenstates $|\pm\rangle = (|B\rangle \pm |0\rangle)/\sqrt{2}$ is separated from the dark states by $\pm \hbar \Omega$. For the light fields of interest, the dark states can be chosen as:

$$
|D_1\rangle = (\sin \varphi |1\rangle' - \cos \varphi |2\rangle') , \qquad (1)
$$

$$
|D_2\rangle = \varepsilon (\cos \varphi |1\rangle' + \sin \varphi |2\rangle') - \sqrt{1 - \varepsilon^2} |3\rangle, \quad (2)
$$

with $|1\rangle' = |1\rangle e^{i\kappa_0(z+x)}$ and $|2\rangle' = |2\rangle e^{i\kappa_0(z-x)}$, where

$$
\varepsilon = |\Omega_3|/\Omega \,, \quad \varphi = \arctan(|\Omega_1|/|\Omega_2|) \tag{3}
$$

hara
terize the relative intensities of the laser beams. The dark states $|D_i\rangle \equiv |D_i(\mathbf{r})\rangle$ are position-dependent due to the spatial variation of the Rabi frequencies $\Omega_i(\mathbf{r})$.

Let us adiabatically eliminate the bright states, so that the atom evolves within the dark-state manifold. The full atomic state vector can then be expanded as $|\Psi(\mathbf{r},t)\rangle = \sum_{n=1}^{2} \chi_n(\mathbf{r},t)|D_n(\mathbf{r})\rangle$, where $\chi_n(\mathbf{r},t)$ describes the motion of an atom in the dark state $|D_n(\mathbf{r})\rangle$. The atomic enter of mass motion is thus represented by a two component wavefunction $\chi = (\chi_1, \chi_2)^T$ obeying [10]

$$
i\hbar \frac{\partial}{\partial t} \chi = \left[\frac{1}{2M} (-i\hbar \nabla - \mathbf{A})^2 + U \right] \chi, \tag{4}
$$

where \bf{A} is the effective vector potential [\[10](#page-3-9), [24,](#page-3-23) [25,](#page-3-24) [26](#page-3-25)] representing a 2×2 matrix whose elements are vectors, ${\bf A}_{n,m} = i\hbar \langle D_n({\bf r}) | \nabla D_m({\bf r}) \rangle$. The particular light field

configuration we have chosen yields

$$
\mathbf{A}_{11} = -\hbar \kappa_0 (\mathbf{e}_z - \cos(2\varphi) \mathbf{e}_x), \tag{5}
$$

$$
\mathbf{A}_{12} = -\hbar \varepsilon (\kappa_0 \sin(2\varphi) \mathbf{e}_x + i \nabla \varphi), \tag{6}
$$

$$
\mathbf{A}_{22} = -\hbar \kappa_0 \varepsilon^2 (\mathbf{e}_z + \cos(2\varphi) \mathbf{e}_x), \tag{7}
$$

with \mathbf{e}_x and \mathbf{e}_z the unit Cartesian vectors. The 2 × 2 matrix U with elements U_{nm} = $(\hbar^2/2M)\langle D_n(\mathbf{r})|\nabla B(\mathbf{r})\rangle\langle B(\mathbf{r})|\nabla D_m(\mathbf{r})\rangle$ is an effective scalar potential; both A and U arise due to the spatial dependen
e of the atomi dark states.

Suppose the incident atom has a velocity \bf{v} much greater than the recoil velocity $v_{\text{rec}} = \hbar \kappa_0 / M \approx$ 0.5m/s for ⁸⁷Rb. In this limit, the laser beams do not significantly change the atom's velocity, permitting a simplified semiclassical approach with no reflected waves. We apply a gauge transformation $\chi(\mathbf{r}, t)$ = $e^{iM{\bf v}\cdot{\bf r}/\hbar-iM{\bf v}^2t/2\hbar}\tilde{\chi}({\bf r},t)$, implying transition to a reference frame moving with velocity **v**, where the twocomponent envelope function $\tilde{\chi}$ varies slowly with r over the atom's wavelength $\lambda = h/(Mv)$. Keeping only terms containing \bf{v} (or its time derivatives), we arrive at the following approximate equation for $\tilde{\chi}$:

$$
i\hbar \left(\partial/\partial t + \mathbf{v} \cdot \nabla\right) \tilde{\chi}(\mathbf{r}, t) = -\mathbf{v} \cdot \mathbf{A}(\mathbf{r}) \tilde{\chi}(\mathbf{r}, t). \qquad (8)
$$

As the omitted scalar potential U and the A^2 term are of the order of the recoil energy $\hbar \omega_{\text{rec}} = \hbar^2 \kappa_0^2 / 2M \ll$ $Mv^2/2$, the fast moving atoms will not feel these potentials. For incident velocities v of the order of v_{rec} or smaller, the atomic motion will undergo a Zitterbewegung [\[16,](#page-3-15) [27](#page-3-26)] which is beyond the scope of the present study. While the atoms must move mu
h faster than the re oil velo
ity, they should also be slow enough to avoid oupling to the bright states. We provide a quantitative analysis of these limitations near the end of the Letter.

In both of the DDT s
hemes to be presented, the operator $\mathbf{v} \cdot \mathbf{A}$ commutes with itself at different times. Going to a moving frame of reference $\mathbf{r}' = \mathbf{r} - \mathbf{v}t$, we can thus relate the wavefunction $\tilde{\chi}$ at time $t = t_f$ to the wavefunction at a previous time $t = t_i$ through

$$
\tilde{\chi}(\mathbf{r}', t_f) = \exp(i\Theta)\tilde{\chi}(\mathbf{r}', t_i).
$$
\n(9)

The 2×2 Hermitian matrix $\Theta = -\hbar^{-1} \int_{t_i}^{t_f} \mathbf{A}(\mathbf{r}' + \mathbf{v}t) \cdot \mathbf{v} dt$ des
ribes the evolution of the internal state of the atom as it traverses the path from $\mathbf{r}_i = \mathbf{r}' + \mathbf{v} t_i$ to $\mathbf{r}_f = \mathbf{r}' + \mathbf{v} t_f$,

$$
\Theta = -\frac{1}{\hbar} \int_{\mathbf{r}_i}^{\mathbf{r}_f} \mathbf{A}(\mathbf{r}) \cdot d\mathbf{r} . \tag{10}
$$

Our subsequent analysis of the atomic dynamics will center on Eqs. $(9)-(10)$ $(9)-(10)$ $(9)-(10)$ and $(5)-(7)$ $(5)-(7)$ $(5)-(7)$.

Atomic analogs of the DDT We first consider the setup depicted in Figs. 1c and [2a](#page-2-0). The atoms are incident along the y axis, along which laser beams 1 and 2

Figure 2: Schematics of the first (a) and second (b) setups for an atomic transistor: The atom, along its trajectories (shown in Figs. $1c,d$) sees the above profile of laser fields.

are relatively shifted $[6, 7, 8, 11]$ $[6, 7, 8, 11]$ $[6, 7, 8, 11]$ $[6, 7, 8, 11]$ $[6, 7, 8, 11]$ $[6, 7, 8, 11]$, so that

$$
A_y = \hbar \sigma_y \varepsilon(y) \partial \varphi(y) / \partial y. \tag{11}
$$

Equations (11) and (10) yield

$$
\Theta = \alpha \sigma_y , \qquad \alpha = -\int_{y_i}^{y_f} \varepsilon(y) \frac{\partial}{\partial y} \varphi(y) dy , \qquad (12)
$$

where α is the mixing angle, σ_y (or σ_x) being the usual Pauli matrix. By taking the initial and final times sufficiently large, we have $y_i \to -\infty$ and $y_f \to +\infty$.

As Figs. 1c and [2a](#page-2-0) show, the first laser beam dominates as the atom enters the gate region, while the second dominates as it exits the region. In between, the atom also feels the third beam. This configuration results in a gateindu
ed rotation of the atom's internal state by a mixing angle α . Specifically, suppose the atom enters the gate region in the internal state $|3\rangle = -|D_2(\mathbf{r}', t_i)\rangle$, with center of mass wave-function $\Phi(\mathbf{r}')$. The atom then exits the gate region in the rotated state

$$
\tilde{\chi}(\mathbf{r}', t_f) = -\Phi(\mathbf{r}') \begin{pmatrix} \sin \alpha \\ \cos \alpha \end{pmatrix} . \tag{13}
$$

Thus, the probability for the atom to emerge in the second dark state is $\cos^2 \alpha$. Note that the second dark state oin
ides with the third internal ground state upon exit: $|D_2(\mathbf{r}', t_f)\rangle = -|3\rangle$. This gate-controlled state rotation is an atomic analog of the action of the DDT. Define $\eta = |\Omega_3|/|\Omega_1|$ as the relative amplitude of the third laser at the central point. The specific relation between α and η depends on the particular choice of light field configuration and is readily derived from Eqs. [\(3\)](#page-1-3) and [\(12\)](#page-2-2). For arbitrary light field configurations, α is a complicated space-dependent function. However for the particular laser configuration we examine here, α simplifies to a function solely depending on η , and η controls α . Fig. [3](#page-2-3) shows the dependence of α on η for Gaussian laser beams. As in the electronic DDT, the transmission coefficient $\cos \alpha$ is independent of the velocity of the incident

Figure 3: The mixing angle α vs. the relative amplitude of the third field η for the first (solid line) and the second (dashed line) setups. The amplitudes of the beams are Gaussian: $|\Omega_1| = a \exp(-(u+\delta)^2/u_1^2), |\Omega_2| = a \exp(-(u-\delta)^2/w_2^2),$ and $|\Omega_3| = a\eta \exp(-u^2/w_3^2 - \delta^2/w_1^2)$, with $u = y$ (first setup) or $u = x$ (second setup). In the first setup, $w_1 = w_2 = w_3 =$ $\delta = 2\lambda$, with $\lambda = 600$ nm being the laser wave length. For the se
ond setup, all the beams are entered at the same point $(\delta = 0)$ and have the widths $w_1 = w_2 = 10w_3 = 20\lambda$.

atoms, so that the transistor properties are robust to a spread in atomic velocities. We estimate the regime of validity of this independen
e near the end of the Letter.

Since $\varepsilon(y) \leq 1$, the mixing angle given by Eq. [\(12\)](#page-2-2) ranges from 0 to $\pi/2$, and the sensitivity $|\Delta\alpha|/|\Delta\eta|$ of the DDT is on the order of unity. Small hanges in the relative Rabi frequency η will thus lead to small changes in the mixing angle: $|\Delta \alpha| \sim |\Delta \eta|$. We next analyze an alternative setup whi
h enables us to reate a more sensitive DDT.

Now suppose that the first two light beams counterpropagate along the x axis with equal intensities (Fig. [1d](#page-0-0)), i.e., $\varphi = \pi/4$ in Eqs. [\(5\)](#page-1-2)-[\(7\)](#page-1-2) for **A**. After the trivial gauge transformation $\exp[i\hbar\kappa_0(1+\varepsilon^2)z\mathbf{I}]$, the light-induced vector potential resembles the Rashba spin orbit oupling whi
h is the spin rotation me
hanism of the ele
troni DDT:

$$
A_z = -\frac{\hbar \kappa_0}{2} (1 - \varepsilon^2) \sigma_z \tag{14}
$$

$$
A_x = -\hbar \kappa_0 \varepsilon \sigma_x, \qquad A_y = 0. \tag{15}
$$

The atomic beam crosses the lasers at an angle in the $x - y$ plane, with initial velocity components $v_x \neq 0$ and v_y . Although the atomic motion in the y direction does not affect the internal state rotation $(A_u = 0)$, sending the beam in at an angle removes the experimental difficulty of having the atoms incident from the same direction as the laser beams. Along its trajectory, the atom feels the laser beam profile illustrated in Fig. [2b](#page-2-0). The evolution matrix of Eq. [\(10\)](#page-1-1) is then

$$
\Theta = \alpha \sigma_x , \qquad \alpha = \kappa_0 \int_{x_i}^{x_f} \varepsilon(x) dx . \tag{16}
$$

Initial and final times are taken sufficiently large that the spatial integration runs from $x_i = -\infty$ to $x_f = +\infty$.

As in the previous s
heme, the intensity of the third laser vanishes $(\varepsilon \rightarrow +0)$ outside the gate region (see Fig. [2b](#page-2-0)). Only the third laser's intensity has significant spatial dependen
e inside the gate region, the intensities of the first two lasers being nearly constant there. In both setups, the ontrolled state rotation arises from the spatial dependen
e of the beams in the gate region. In the first setup the variation is in the lasers' relative intensities. Contrastingly, in the second setup, the intensities of the first two lasers are constant in the gate region, so the ontrolled state rotation is driven by only the relative phases of the ounterpropagating laser beams.

As in the previous setup, the atom enters the gate region in the internal state $|3\rangle = -|D_2(\mathbf{r}',t_i)\rangle$ and with center of mass wave-function $\Phi(\mathbf{r}')$. The atom exits in the rotated state

$$
\tilde{\Psi}(\mathbf{r}', t_f) = -\tilde{\chi}(\mathbf{r}') \begin{pmatrix} i \sin \alpha \\ \cos \alpha \end{pmatrix}, \qquad (17)
$$

where the mixing angle α is controlled by the variation of the relative intensity of the third laser beam.

To estimate the mixing angle, suppose that Ω_3 , and hence ε , do not change significantly in the gate region. Equation [\(16\)](#page-2-4) then gives $\alpha = \kappa_0 \bar{\varepsilon}L$, where L (see Fig. [2b](#page-2-0)) is the length of the area in whi
h the third laser has the strongest intensity. Note that the mixing angle is now proportional to L , as well as to the average strength $\kappa_0 \bar{\varepsilon}$ of the spin-orbit coupling. This behavior is in direct analogy to the electronic DDT [1]. As in Eq. (2) of [1], the output power of the atoms in the internal state $|3\rangle$ is $P = \cos^2 \alpha = \cos^2(\kappa_0 \bar{\varepsilon}L)$. Using this atomic setup, $\alpha = \kappa_0 \bar{\varepsilon} L$ can be much larger than $\pi/2$, provided $L \gg$ $(\kappa_0 \bar{\varepsilon})^{-1}$, as shown in Fig. [3.](#page-2-3) Small changes in the relative amplitude of the third laser $\eta = |\Omega_3|/|\Omega_1|$ can therefore yield substantial changes in the mixing angle: $|\Delta \alpha| \sim$ $|\Delta \eta| \kappa_0 L$. The sensitivity of such a DDT, $|\Delta \alpha|/|\Delta \eta| \sim$ $\kappa_0 L$, can far exceed unity if L is much greater than the optical wave-length $\lambda = 2\pi/\kappa_0$.

Let us estimate the range of atomic beam velocities for which our approximations are valid. The atom crosses the gate region in a time $\tau = L/v$. Due to nonadiabatic oupling to the bright states, the dark state atoms have the finite lifetime $\tau_D \, = \, \Omega^2/\gamma \Delta \omega^2$ [28], where γ is the excited state decay rate and $\Delta \omega = v \partial \varphi / \partial y \sim v \pi / L$ (first setup), or $\Delta\omega = v\kappa_0$ (second setup). The frequency shift $\Delta\omega$ represents the two-photon detuning due to the finite time of the atom-light interaction (first setup) or the twophoton Doppler shift (se
ond setup). To avoid de
ay, we require the beam to be in the adiabatic limit, i.e. $\tau/\tau_D \ll 1$. Taking $\Omega = 2\pi \times 10^7$ Hz [\[29](#page-3-28)], $\gamma = 10^7$ s⁻¹, $\kappa_0 = 2\pi/\lambda$, $\lambda = 600$ nm and $L = 4\lambda$, we require atomic velocities $v \ll 100 \,\mathrm{m/s}$ for the first setup and $v \ll 1 \,\mathrm{m/s}$ for the second setup. The increased sensitivity in the second scheme thus comes at the expense of increased non-adiabati losses.

Ultra
old atoms are highly tunable and ontrollable,

and can thus serve as quantum simulators for a variety of other systems, in
luding systems whi
h have yet to be experimentally accessed in their original manifestations. In this Letter, we have identified an atomic analog of one such system, the spin field-effect transistor. Our atomic transistors, like their electronic counterpart, provide controllable state manipulation that is relatively insensitive to the thermal spread of beam velocities. The devices we have proposed are based on the familiar tripod STIRAP configuration, and appear to be feasible within current experimental pro
edures.

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